



TK55D10J1(Q) Information

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For Reference Only

Part Number TK55D10J1(Q)

ManufacturerToshiba Semiconductor and StorageCategoryDiscrete Semiconductor ProductsTransistors - FETs, MOSFETs - Single

Description MOSFET N-CH 100V 55A TO220W

Package TO-220-3

For the pricing/inventory/lead time, please contact

us

Website: https://www.heisener.com E-mail: salesdept@heisener.com



Request a Quote

Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.









TK55D10J1(Q) Specifications

Manufacturer Part Number	TK55D10J1(Q)
Manufacturer	Toshiba Semiconductor and Storage
Category	Discrete Semiconductor Products
	Transistors - FETs, MOSFETs - Single
Package	TO-220-3
Series	-
FET Type	N-Channel
Technology	MOSFET (Metal Oxide)
Drain to Source Voltage (Vdss)	100V
Current - Continuous Drain (Id) @ 25°C	55A (Ta)
Drive Voltage (Max Rds On, Min Rds On)	4.5V, 10V
Vgs(th) (Max) @ Id	2.3V @ 1mA
Gate Charge (Qg) (Max) @ Vgs	110nC @ 10V
Input Capacitance (Ciss) (Max) @ Vds	5700pF @ 10V
Vgs (Max)	±20V
FET Feature	-
Power Dissipation (Max)	140W (Tc)
Rds On (Max) @ Id, Vgs	10.5 mOhm @ 27A, 10V
Operating Temperature	150°C (TJ)
Mounting Type	Through Hole
Supplier Device Package	TO-220(W)
Package / Case	TO-220-3
	Report errors?

TK55D10J1(Q) Guarantees



Quality Guarantees

We provide 90 days warranty. *

If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.



Service Guarantees

We guarantee 100% customer satisfaction.

Our experienced sales team and tech support team back our services to satisfy all our customers.

TK55D10J1(Q) Payment Methods



















TK55D10J1(Q) Shipping Methods













If you have any question about TK55D10J1(Q), please do not hesitate to contact us!

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